

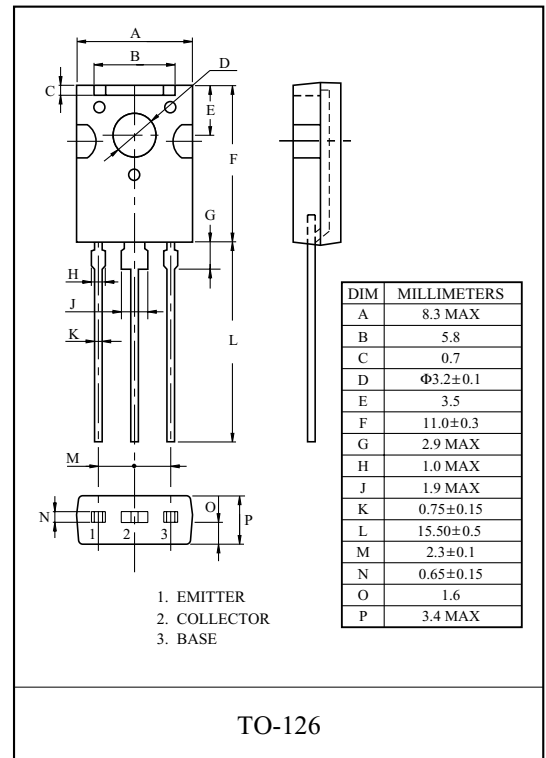
SWITCHING REGULATOR APPLICATION.
HIGH VOLTAGE AND HIGH SPEED
SWITCHING APPLICATION.

FEATURES

- Excellent Switching Times
: $t_{on}=1.1\mu\text{s(Typ.)}$, $t_f=0.7\mu\text{s(Typ.)}$, at $I_C=1\text{A}$
- High Collector Voltage : $V_{CBO}=900\text{V}$.

MAXIMUM RATING (Ta=25 °C)

CHARACTERISTIC		SYMBOL	RATING	UNIT
Collector-Base Voltage		V_{CBO}	900	V
Collector-Emitter Voltage		V_{CEO}	530	V
Emitter-Base Voltage		V_{EBO}	9	V
Collector Current	DC	I_C	1.5	A
	Pulse	I_{CP}	3	
Base Current		I_B	0.75	A
Collector Power Dissipation (Tc=25 °C)		P_C	20	W
Junction Temperature		T_j	150	°C
Storage Temperature Range		T_{stg}	-55 ~ 150	°C



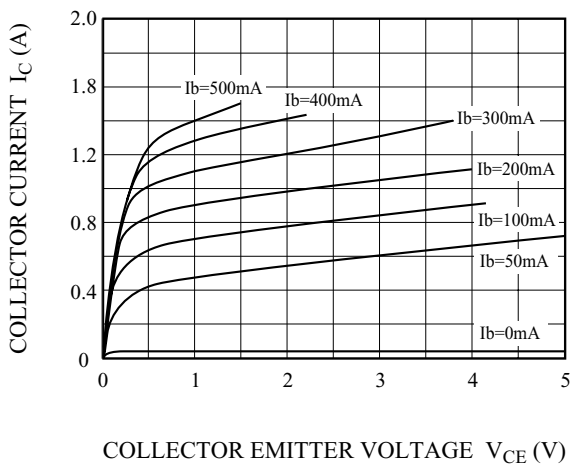
ELECTRICAL CHARACTERISTICS (Ta=25 °C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Emitter Cut-off Current	I_{EBO}	$V_{EB}=9\text{V}$, $I_C=0$	-	-	10	μA
DC Current Gain	$h_{FE}(1)$	$V_{CE}=10\text{V}$, $I_C=10\text{mA}$	15	-	50	
	* $h_{FE}(2)$	$V_{CE}=10\text{V}$, $I_C=0.4\text{A}$	20	-	50	
	$h_{FE}(3)$	$V_{CE}=10\text{V}$, $I_C=1\text{A}$	6	-	-	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=0.5\text{A}$, $I_B=0.1\text{A}$	-	-	0.8	V
		$I_C=1.5\text{A}$, $I_B=0.5\text{A}$	-	-	2.5	
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=0.5\text{A}$, $I_B=0.1\text{A}$	-	-	1	V
		$I_C=1\text{A}$, $I_B=0.25\text{A}$	-	-	1.2	
Collector Output Capacitance	C_{ob}	$V_{CB}=10\text{V}$, $f=0.1\text{MHz}$, $I_E=0$	-	21	-	pF
Transition Frequency	f_T	$V_{CE}=10\text{V}$, $I_C=0.1\text{A}$	4	-	-	MHz
Turn-On Time	t_{on}	<p>$I_{B1}=I_{B2}=0.2\text{A}$ DUTY CYCLE $\leq 2\%$</p>	-	1.1	-	μs
Storage Time	t_{stg}		-	3.0	-	μs
Fall Time	t_f		-	0.7	-	μs

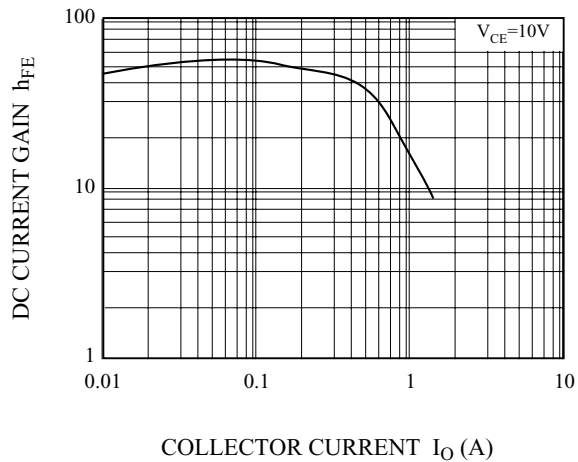
*Note : h_{FE} Classification R:20~30, O:25~35, Y:30~50

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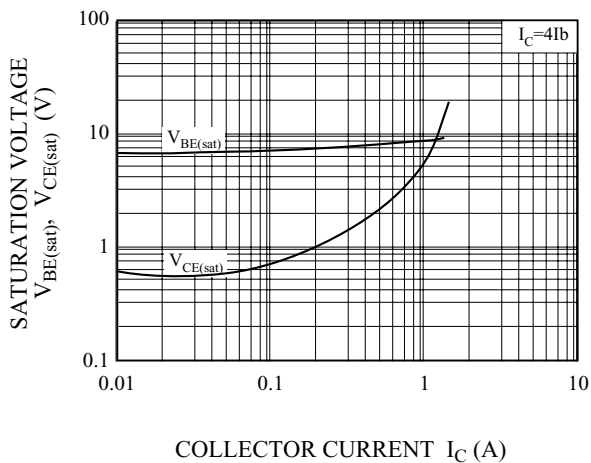
STATIC CHARACTERISTIC



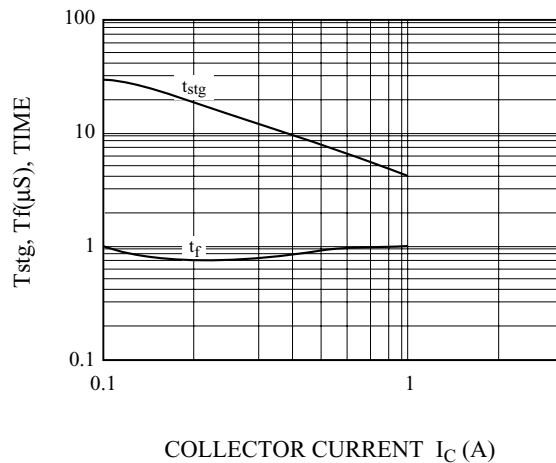
DC CURRENT GAIN



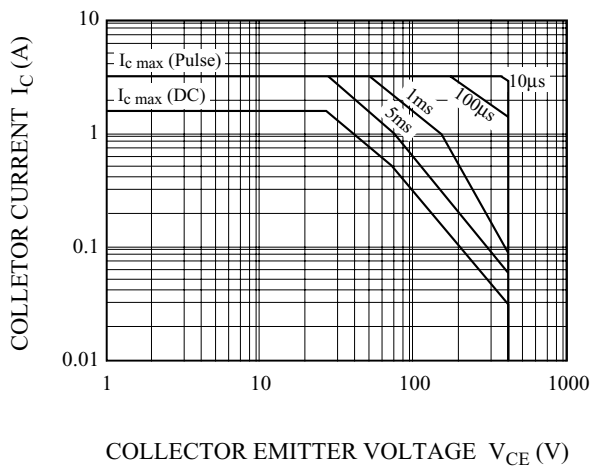
$V_{CE(sat)}$ vs. $V_{BE(sat)}$



SWITCHING TIME



SAFE OPERATING AREA



$P_C - T_a$

